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CLAIMS

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- 1	Δne	lectret	condenser	COMPRESIDO
_•	·	100000	-conduction	, comprising:

- a first film including a first electrode;
- a second film including a second electrode and an electret film;
- a first insulting film formed between the first film and the second film; and an air gap formed by removing part of the first insulating film,

wherein respective parts of the first film and the second film exposed in the air gap are formed of a second insulating film.

10 2. (Amended) The electret condenser of Claim 1,

wherein at least one of the first film and the second film has a through hole communicating with the air gap.

- 3. The electret condenser of Claim 1,
- wherein the second insulating film is an insulating film having tensile stress.
 - 4. The electret condenser of Claim 1, wherein the second insulating film is a silicon nitride film.
- 5. The electret condenser of Claim 1,
 wherein the first insulating film is a lamination layer of a plurality of insulating
 - 6. The electret condenser of Claim 1,

films made of the same material.

wherein the first film is a fixed film, and the second film is a vibrating film.